

L Number	Hits	Search Text	DB	Time stamp
4	2	((("6433384") or ("6472701")).PN.	USPAT	2003/10/16 09:44
5	65	("ONO") same (masking or protect\$5) same ((silicon adj nitride) or ("SiN")) same (pattern\$6 or (wet adj etch\$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/16 09:47
6	63	("ONO") same (masking or protect\$5) same ((silicon adj nitride) or ("SiN")) same (pattern\$6 or (wet adj etch\$6)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/16 09:47
-	12	((("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")).PN.	USPAT	2003/10/15 14:43
-	2	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and (ono same (wet adj etching) same (dop\$6 or implant\$6) same (buried adj bit adj line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:33
-	2	(ono same (wet adj etching) same (dop\$6 or implant\$6) same (buried adj bit adj line)) and ((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:12
-	3	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (wet adj etching) and (dop\$6 or implant\$6) and (buried adj bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:15
-	8	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (wet adj etching) and (dop\$6 or implant\$6) and (bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:27
-	94	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:33
-	94	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:34
-	81	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and bit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:29
-	72	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:34
-	2	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or nrom) and (ono same (wet adj etching) same (dop\$6 or implant\$6) same (buried adj bit adj line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:33
-	157	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:33
-	150	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 14:34

-	115	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:46
-	85	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bit adj line)) and (etch\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:49
-	24	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bit adj line)) and (wet adj etch\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:48
-	30	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bur\$4 adj bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:47
-	6	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bit adj line)) and (wet adj etch\$5)) and (bur\$4 adj bit adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:47
-	6	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bur\$4 adj bit adj line)) and (wet adj etch\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:49
-	26	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6) ) and @ad<=20021115) and (bur\$4 adj bit adj line)) and (etch\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 07:57
-	99	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or (NROM)) and ((ono or (oxide adj nitride adj oxide) or ((silicon adj oxide) adj (silicon adj nitride) adj (silicon adj oxide))) and (dop\$6 or implant\$6) and @ad<=20021115) and (bit adj line) and (word adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:52
-	1	("6566203").PN.	USPAT	2003/10/09 15:34
-	1	("6461906").PN.	USPAT	2003/09/03 13:17
-	1	("5496753").PN.	USPAT	2003/09/03 13:07
-	329	(438/261).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 13:07
-	1390	(438/257).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 13:09
-	578	(438/258).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 13:08
-	330	(438/259).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 13:08
-	98	(438/260).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 13:08

-	329	(438/261).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:08
-	199	(438/262).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:08
-	711	(438/526).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:09
-	694	(438/275).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:09
-	246	(438/294).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:10
-	152	(438/216).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:10
-	333	(438/591).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:10
-	152	(438/216).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:10
-	613	(438/264).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:11
-	636	(438/527).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:12
-	750	(438/287).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:12
-	74	(438/954).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 13:12
-	20	semiconductor same ono same (etch\$4 adj stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 15:28
-	20	(semiconductor same ono same (etch\$4 adj stop)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 15:27

-	480	semiconductor and ono and (etch adj stop) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:21
-	12	438/287,261,591.ccls. and ono and (etch adj stop) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:37
-	264	438/287,261,591.ccls. and ono and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 15:38
-	397	257/\$.ccls. and ono and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:52
-	340	438/\$.ccls. and ono and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:52
-	502	ono and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:53
-	9	(ono same semiconductor same (etch\$3 adj stop\$4 adj (layer or film))) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 14:53
-	478	ono and semiconductor and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:34
-	32968	liu.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:36
-	10	liu.in. and cheng-jye	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:35
-	2054	hsiung.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:36
-	66294	chen.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:36
-	3	hsiung.in. and tai-liang	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:37
-	32	chen.in. and chia-hsing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 15:37
-	1	("6376341").PN.	USPAT	2003/10/10 11:29

-	3	(( "6566203" ) or ( "6461906" ) or ( "5496753" ) ).PN.	USPAT	2003/10/10 10:48
-	13	(( "6429063" ) or ( "6417044" ) or ( "6399441" ) or ( "6395590" ) or ( "6372564" ) or ( "6346466" ) or ( "6255166" ) or ( "6583007" ) or ( "6566203" ) or ( "6555427" ) or ( "6518125" ) or ( "6482708" ) or ( "6376341" ) ).PN.	USPAT	2003/10/15 14:49
-	14	(( "6429063" ) or ( "6417044" ) or ( "6399441" ) or ( "6395590" ) or ( "6372564" ) or ( "6346466" ) or ( "6255166" ) or ( "6583007" ) or ( "6566203" ) or ( "6555427" ) or ( "6518125" ) or ( "6482708" ) or ( "6376341" ) or ( "6538270" ) ).PN.	USPAT	2003/10/16 09:22